TDA2002

8W CAR RADIO AUDIO AMPLIFIER

Protection against:

b) thermal over range;c) fortuitous open ground;

d) load dump voltage surge.

a) short circuit;

NOT FOR NEW DESIGN

The TDA2002 is a class B audio power amplifier in Pentawatt[®] package designed for driving low impedance loads (down to 1.6Ω).

SGS-THOMSON MICROELECTRONICS

The device provides a high output current capability (up to 3.5A), very low harmonic and cross-over distortion.

In addition, the device offers the following features:

- very low number of external components
- assembly ease, due to Pentawatt[®] power package with no electrical insulation requirement
- space and cost saving
- high reliability
- flexibility in use

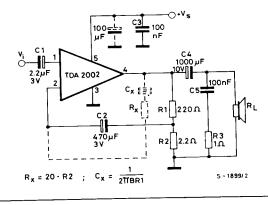
ABSOLUTE MAXIMUM RATINGS

ORDER CODE: TDA2002H (Hor. Pentawatt) TDA2002V (Ver. Pentawatt)

See TDA 2003 for more complete information.

ADOUL			
V _s	Peak supply voltage (50 ms) DC supply voltage	40 28	V V
V _s V _s I _o I-	Operating supply voltage Output peak current (repetitive) Output peak current (non repetitive)	18 3.5 4.5 15	A A W
P _{tot} T _{stg} , T _j	Power dissipation at $T_{case} = 90^{\circ}C$ Storage and junction temperature	-40 to 150	°C

Fig. 1 - Application circuit



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1/2 531

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ELECTRICAL CHARACTERISTICS ($V_s = 14.4V$, $T_{amb} = 25^{\circ}C$ unless otherwise specified)

Parameter	Test conditions	Min.	Тур.	Max.	Unit
DC CHARACTERISTICS (Befer to DC t	est circuit)				

DC CHARACTERISTICS (Refer to DC test circuit)

V _s	Supply voltage	8		18	V
Vo	Quiescent output voltage (pin 4)	6.1	6.9	7.7	V
Id	Quiescent drain current (pin 5)		45	80	mA

AC CHARACTERISTICS (Refer to AC test circuit, G_v = 40 dB)

Po	Output power		d = 10%	f = 1 kHz RL= 4Ω RI = 2Ω	4.8 7	5.2 8		w
			V _s = 16V	R _L = 4Ω R _L = 2Ω		6.5 10		w w
V _{i (rms)}	Input saturation voltage				300			mV
Vi	Input sensitivity		$P_{o} = 0.5W$ $P_{o} = 0.5W$ $P_{o} = 5.2W$ $P_{o} = 8W$	$f = 1 \text{ kHz}$ $R_{L} = 4\Omega$ $R_{L} = 2\Omega$ $R_{L} = 4\Omega$ $R_{L} = 2\Omega$		15 11 55 50		mV mV mV mV
В	Frequency response (-3 dB)		R _L = 4Ω	P _o = 1W	40 to 15 000			Hz
d	Distortion		$P_o = 0.05 \text{ to } 3$ $P_o = 0.05 \text{ to } 5$	f = 1 kHz $8.5W \text{ R}_{L} = 4\Omega$ $5W \text{ R}_{L} = 2\Omega$		0.2 0.2		% %
Ri	Input resistance (pin 1)		f = 1 kHz		70	150		kΩ
Gv	Voltage gain (open loop)		R _L = 4Ω	f = 1 kHz		80		dB
Gv	Voltage gain (closed loop)		R _L = 4Ω	f = 1 kHz	39.3	40	40.5	dB
e _N	Input noise voltage	(*)				4		μV
İN	Input noise current	(*)]			60		pА
η	Efficiency		$P_o = 5.2W$ $P_o \approx 8W$	f = 1 kHz R _L = 4Ω R _L = 2Ω		68 58		% %
SVR	Supply voltage rejection		R _L = 4Ω R _g = 10 kΩ f _{ripple} = 100 H	ίz	30	35		dB

(*) Filter with noise bandwidth: 22 Hz to 22 KHz.

2/2 532

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Datasheets for electronics components.